



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

FEB -8 2002

TC 2800 MAIL ROOM

In re Patent Application of

TOYOSAWA et al

Atty. Ref.: 1035-270

Serial No. 09/598,169

Group: 2811

Filed: June 21, 2000

Examiner: Vu, H.

For: A SEMICONDUCTOR DEVICE HAVING ACTIVE
ELEMENT CONNECTED TO AN ELECTRODE
METAL PAD VIA A BARRIER METAL LAYER
AND INTERLAYER INSULATING FILM

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February 4, 2002

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

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AMENDMENT

Responsive to the Official Action dated October 4, 2001 (for which petition is
hereby made for a one month extension of time), please amend the above-identified
application as follows:

IN THE CLAIMS

Please substitute the following amended claims 14, 15, 16, 22 and 25 for
corresponding claims previously presented. A copy of the amended claims showing
current revisions is attached.

B1 Sub DI
14. (Amended) A semiconductor device, comprising:
an active element provided on a semiconductor substrate, said active element
including at least two diffusion layers and a gate electrode;